

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	100	"5521735" "5444802" "4831631" "5682401" "4772787" "4801189" "4871223" "4878723" "4961618" "5255111" "5327448" "5403775" "5511084" "4997246" "5329137" "5350931" "6091267" "6479844" "7012274" "4867522" "5357591" "6128428" "4284663" "5214487" "5272711" "5307200" "4923264" "4922500" "5333220" "5515461" "5703989" "4756587" "4778235" "5208183" "5488679" "5594824" "5673284" "5684820" "5703895" "5799119" "5859866" "5878070" "5937118" "6064783" "4414488" "4453802" "4464762" "4492425" "4603940" "4630889").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/31 13:45
S2	6	"5105232" "5768378" "6393185").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/31 14:31
S3	50	(US-4503541-\$ or US-5259044-\$ or US-4568890-\$ or US-4631494-\$ or US-4991926-\$ or US-5199086-\$ or US-5230028-\$ or US-5309532-\$ or US-5323406-\$ or US-5359449-\$ or US-5412471-\$ or US- 5424863-\$ or US-5495359-\$ or US-5526448-\$ or US-5528707-\$ or US-5561397-\$ or US-5652807-\$ or US-5878066-\$ or US-5907426-\$ or US-5946336-\$ or US-5953466-\$ or US-5960135-\$ or US-5963357-\$ or US-6115116-\$ or US-6122414-\$ or US-3631331-\$).did. or (US- 3613013-\$ or US-3571750-\$ or US-3913035-\$ or US-4286229-\$ or US-4294513-\$ or US-4297651-\$ or US-4334202-\$ or US-4342009-\$ or US-4394660-\$ or US-4447116-\$ or US-4450541-\$ or US-4453802-\$ or US-4462007-\$ or US-4495704-\$ or US-4518931-\$ or US- 4521747-\$ or US-4521110-\$ or US-4521069-\$ or US-4533886-\$ or US-4564824-\$ or US-4571555-\$ or US-4575851-\$ or US-4607909-\$ or US-4614919-\$).did.	USPAT	OR	ON	2008/03/31 16:19

S4	27	257/9,20,23,24.ccls. and ((quantum waveguide) adj1 (gate semiconductor))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/04/01 08:43
S5	1	257/9,20,23,24.ccls. and (gate semiconductor transistor) and ((multiple multi\$3 plural\$3 two) near2 (waveguide ((laser light) adj (beam)))) and (((voltage electrical megnetic current) adj (bias supply)) with (gate))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/04/01 09:21
S6	41	385/2,130,28,49,15,27,30,16,14,1,37,123,41,48,8.ccls. and (gate semiconductor transistor) and ((multiple multi\$3 plural\$3 two) near2 (waveguide ((laser light) adj (beam)))) and (((voltage electrical megnetic current) adj (bias supply)) with (gate))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/04/01 09:36
S9	61	438/31,32.ccls. and (gate semiconductor transistor) same ((multiple multi\$3 plural\$3 two) near2 (waveguide ((laser light) adj (beam))))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/04/01 10:14
S8	149	438/31,32.ccls. and (gate semiconductor transistor) and ((multiple multi\$3 plural\$3 two) near2 (waveguide ((laser light) adj (beam))))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/04/01 10:14
S12	117	372/50.11,50.12,64.ccls. and (gate semiconductor transistor) same ((multiple multi\$3 plural\$3 two) near2 (waveguide ((laser light) adj (beam))))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/04/01 10:16

S11	257	372/50.11,50.12,64.ccls. and (gate semiconductor transistor) and ((multiple multi\$3 plural\$3 two) near2 (waveguide ((laser light) adj (beam))))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/04/01 10:16
S14	4	398/212,138.ccls. and (gate semiconductor transistor) same ((multiple multi\$3 plural\$3 two) near2 (waveguide ((laser light) adj (beam))))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/04/01 10:17
S15	0	380/256,255.ccls. and (gate semiconductor transistor) same ((multiple multi\$3 plural\$3 two) near2 (waveguide ((laser light) adj (beam))))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/04/01 10:19
S16	5	380/256,255.ccls. and ((quantum waveguide) adj1 (gate semiconductor))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/04/01 10:21
S18	0	713/150,151.ccls. and ((quantum waveguide) adj1 (gate semiconductor))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/04/01 10:44
S19	7094	(gate semiconductor transistor) same ((multiple multi\$3 plural\$3 two) near2 (waveguide ((laser light) adj (beam))))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/04/01 10:46

S20	1	S19 and (((voltage electrical megnetic current) adj (bias supply)) with (gate)) and (tunnel\$3 with (coupl\$3 well))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/04/01 10:47
S21	72	S19 and (((voltage electrical megnetic current) adj (bias supply)) with (gate))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/04/01 10:49
S23	2	"6834348".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/04/01 11:16
S22	2	"6668246".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/04/01 11:16
S26	1	S19 and (((magnetic) near1 (bias supply)) with (gate))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/04/01 12:27
S28	14	(((magnetic) adj (bias supply)) with (gate))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/04/01 12:29

L1	870	"359"/\$.ccls. and (gate semiconductor transistor) same ((multiple multi \$3 plural\$3 two) near2 (waveguide ((laser light) adj (beam))))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/04/02 08:44
L2	8	l1 and (((voltage electrical magnetic current) adj (bias supply)) with (gate))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/04/02 08:45

4/2/2008 9:20:06 AM**C:\Documents and Settings\npatel5\My Documents\EAST\Workspaces\FY_08\WorkSpace_694.wsp**